Multiple interfaces induced evolution of electromagnetic patterns for efficient microwave absorption at low thickness

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Figure S1. SEM- EDS spectra of (a-b) Mo-Ni₂P/rGO-700.



Figure S2. SEM image of NiMoO₄/rGO precursors synthesized with 2 mL GO solution.



Figure S3. SEM images of (a-c) Mo-Ni₂P/rGO-600 at different magnification factors.



Figure S4. SEM images of (a-c) Mo-Ni₂P/rGO-800 at different magnification factors.

	Bandwidth / GHz	Thickness / mm	Ref.
2H-MoS ₂ /rGO	4.0	2.5	10
graphene@CNTs	3.3	3.0	11
CoNi-P/C-400	4.5	2.1	27
CoNi-P/C-300	3.5	2.1	27
PVDF/rGO	4.3	4.0	30
rGO/MnFe ₂ O ₄	4.9	3.0	31
rGO/Ni	4.2	2.0	32
Co/CNTs/CS	4.1	2.2	33
graphene@CuS	4.5	2.5	34
Co/C	3.8	2.0	35
FeCo/C	5.5	2.4	36
γ-Fe ₂ O ₃ /rGO	3.0	2.5	37
Mo-Ni ₂ P/rGO-700	5.24	1.8	This work
Mo-Ni ₂ P/rGO-800	3.48	1.2	This work

Table S1. Microwave absorption property of the reported work and this work